Si PIN photodiode **\$5971, \$5972, \$5973 series**

High-speed photodiodes (S5973 series: 1.5 GHz)



S5971, S5972 and S5973 series are high-speed Si PIN photodiodes designed for visible to near infrared light detection. These photodiodes provide wideband characteristics at a low bias, making them suitable for optical communications and other high-speed photometry. S5973 series includes a mini-lens type (S5973-01) that can be efficiently coupled to an optical fiber and a violet sensitivity enhanced type (S5973-02) ideal for violet laser detection.

Features

High-speed response

\$5971 : 100 MHz (VR=10 V) \$5972 : 500 MHz (VR=10 V) \$5973 series: 1 GHz (VR=3.3 V)

Low priceHigh sensitivity

S5973-02: 0.3 A/W, QE=91 % (λ=410 nm)

High reliability

Applications

- Optical fiber communications
- High-speed photometry
- Violet laser detection (S5973-02)

■ General ratings / Absolute maximum ratings

General ratings / Absolute maximum ratings											
Type No.	Dimensional outline/ Window material *1	Package	Active area size		Absolute maximum ratings						
				Effective	Reverse	Power	Operating	Storage			
				active area	voltage	dissipation	temperature	temperature			
					VR Max.	Р	Topr	Tstg			
		(mm)	(mm)	(mm²)	(V)	(mW)	(°C)	(°C)			
S5971			φ1.2	1.1							
S5972	①/ K		φ0.8	0.5							
S5973		TO-18			20	50	-40 to +100	-55 to +125			
S5973-01	2/L		φ0.4	0.12							
S5973-02	3/K					ı					

■ Electrical and optical characteristics

			Photo sensitivity			Short			Temp.				
	Spectral	ectral Peak		S			circuit	Da	ark	coefficient	Cut-off	Terminal	NEP
	response	sensitivity		(A/	W)		current	curi	rent	of	frequency	capacitance	VR=10 V
Type No.	range	wavelength					Isc	- 11	D	ID	fc	Ct	λ=λρ
	λ	λр	1 n	660	780	830	100 <i>lx</i>			TCID		f=1 MHz	
			λр	nm	nm	nm		Тур.	Max.				
	(nm)	(nm)					(µA)	(nA)	(nA)	(times/°C)	(GHz)	(pF)	(W/Hz ^{1/2})
S5971	320 to 1060	900	0.64		0.55	0.6	1.0	0.07 *3	1 * ³		0.1 * ³	3 * ³	7.4 × 10 ⁻¹⁵
S5972		800	0.57	0.44		0.55	0.42	0.01 *3	0.5 *3	4.45	0.5 *3		3.1 × 10 ⁻¹⁵
S5973	320 to		0.52		0.51	0.47	0.09			1.15			1.1 × 10 ⁻¹⁵ * ⁴
S5973-01	1000	760				0.47	0.42	0.001 *4	0.1 *4		1.5 * ⁴	1.6 **	
S5973-02			0.45	0.3 *2	0.42	0.37	0.09						1.9 × 10 ⁻¹⁵ * ^{2, *4}

^{*1:} Window material K: borosilicate glass, L: lens type borosilicate glass



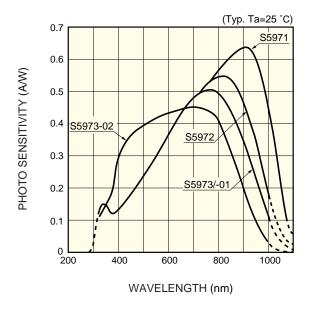
^{*2:} λ=410 nm

^{*3:} VR=10 V

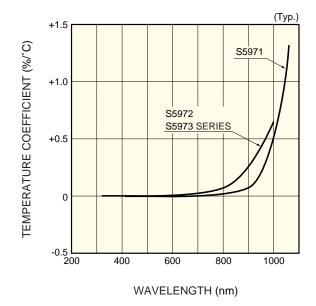
^{*4:} VR=3.3 V

Si PIN photodiode S5971, S5972, S5973 series

■ Spectral response

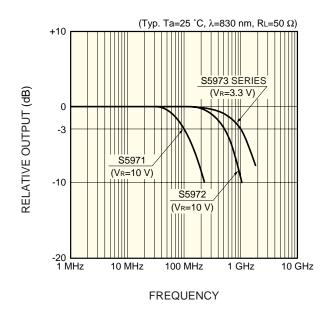


■ Photo sensitivity temperature characteristics

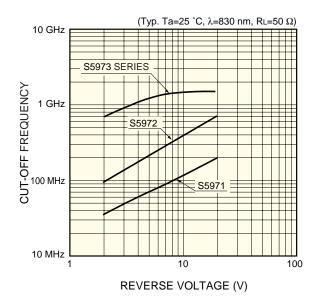


KPINB0157EA KPINB0158EA

■ Frequency response



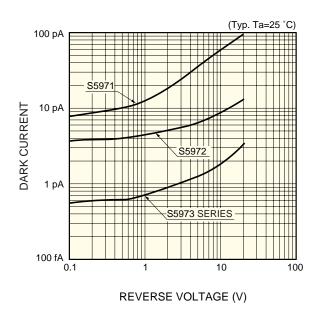
■ Cut-off frequency vs. reverse voltage



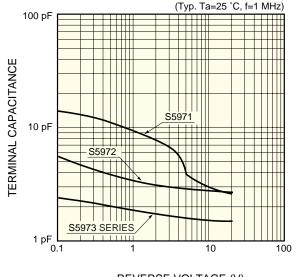
KPINB0159EB KPINB0160EI

Si PIN photodiode S5971, S5972, S5973 series

■ Dark current vs. reverse voltage



■ Terminal capacitance vs. reverse voltage



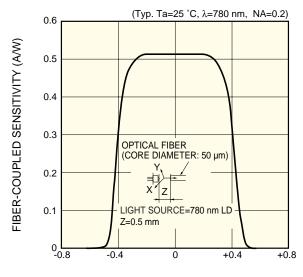
REVERSE VOLTAGE (V)

KPINR0162F∆

KPINB0161EA

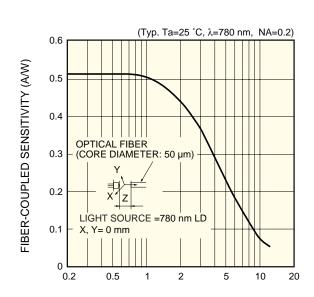
■ Fiber coupling characteristics (S5973-01)

X, Y direction



SHIFT FROM LENS CENTER X, Y (mm)

Z direction

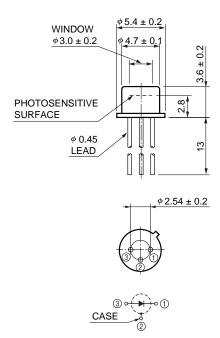


DISTANCE BETWEEN LENS AND FIBER END Z (mm)

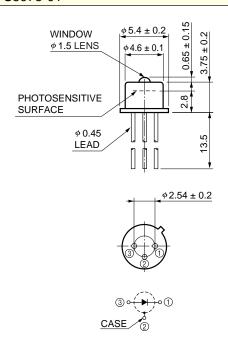
KPINBO089FA KPINBO089FA

■ Dimensional outlines (unit: mm)

① S5971, S5972, S5973

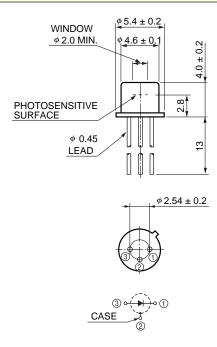


2 S5973-01



KPINA0023EA

3 S5973-02



KPINA0061EA

KPINA0022EB

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